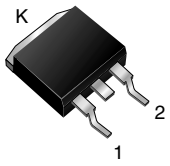
VBT3045C

Vishay General Semiconductor

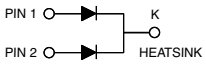
Dual Low-Voltage Trench MOS Barrier Schottky Rectifier

Ultra Low V_F = 0.30 V at I_F = 5.0 A

TMBS®
TO-263AB



VBT3045C



FEATURES

- Trench MOS Schottky technology
- Low forward voltage drop, low power losses
- High efficiency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C
- Not recommended for PCB bottom side wave mounting
- Compliant to RoHS Directive 2002/95/EC and in accordance to WEEE 2002/96/EC

Pb e3 **RoHS** COMPLIANT

TYPICAL APPLICATIONS

For use in high frequency DC/DC converters, switching power supplies, freewheeling diodes, OR-ing diode, and reverse battery protection.

PRIMARY CHARACTERISTICS	
$I_{F(AV)}$	2 x 15 A
V_{RRM}	45 V
I_{FSM}	200 A
V_F at I_F = 15 A	0.39 V
T_J max.	150 °C

MECHANICAL DATA

Case: TO-263AB
Molding compound meets UL 94 V-0 flammability rating
Base P/N-E3 - RoHS compliant, commercial grade

Terminals: Matte tin plated leads, solderable per J-STD-002 and JESD 22-B102
E3 suffix meets JESD 201 class 1A whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs maximum

MAXIMUM RATINGS (T_A = 25 °C unless otherwise noted)				
PARAMETER		**SYMBOL**	**VBT3045C**	**UNIT**
Maximum repetitive peak reverse voltage		V_{RRM}	45	V
Maximum average forward rectified current (fig. 1)	per device	$I_{F(AV)}$	30	A
	per diode		15	
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load		I_{FSM}	200	A
Operating junction and storage temperature range		T_J, T_{STG}	- 40 to + 150	°C

For technical questions within your region, please contact one of the following:
DiodesAmericas@vishay.com, DiodesAsia@vishay.com, DiodesEurope@vishay.com

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ELECTRICAL CHARACTERISTICS (T_A = 25 °C unless otherwise noted)						
PARAMETER	**TEST CONDITIONS**		**SYMBOL**	**TYP.**	**MIN.**	**UNIT**
Instantaneous forward voltage per diode	I_F = 5 A	T_A = 25 °C	V_F (1)	0.42	-	V
	I_F = 7.5 A			0.44	-	
	I_F = 15 A			0.49	0.57	
	I_F = 5 A	T_A = 125 °C		0.30	-	
	I_F = 7.5 A			0.33	-	
	I_F = 15 A			0.39	0.48	
Reverse current per diode	V_R = 45 V	T_A = 25 °C	I_R (2)	-	2000	µA
		T_A = 125 °C		17	50	mA

Notes

(1) Pulse test: 300 µs pulse width, 1 % duty cycle

(2) Pulse test: Pulse width ≤ 40 ms

THERMAL CHARACTERISTICS (T_A = 25 °C unless otherwise noted)				
PARAMETER		**SYMBOL**	**VBT3045C**	**UNIT**
Typical thermal resistance	per diode	$R_{\theta JC}$	1.6	°C/W
	per device		0.85	

ORDERING INFORMATION (Example)					
PACKAGE	**PREFERRED P/N**	**UNIT WEIGHT (g)**	**PACKAGE CODE**	**BASE QUANTITY**	**DELIVERY MODE**
TO-263AB	VBT3045C-E3/4W	1.38	4W	50/tube	Tube
TO-263AB	VBT3045C-E3/8W	1.38	8W	800/reel	Tape and reel

RATINGS AND CHARACTERISTICS CURVES

(T_A = 25 °C unless otherwise noted)

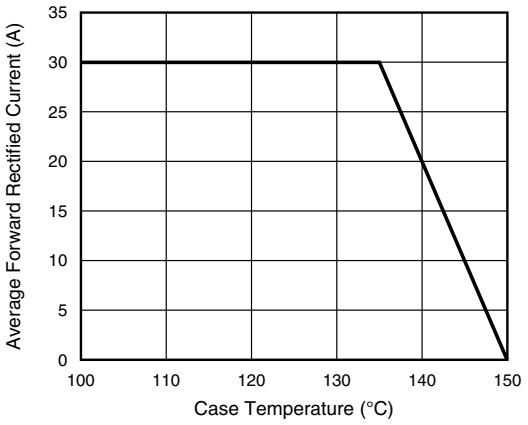


Fig. 1 - Maximum Forward Current Derating Curve

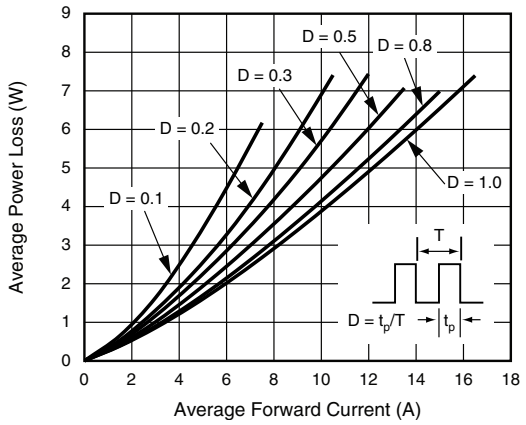


Fig. 2 - Forward Power Loss Characteristics Per Diode

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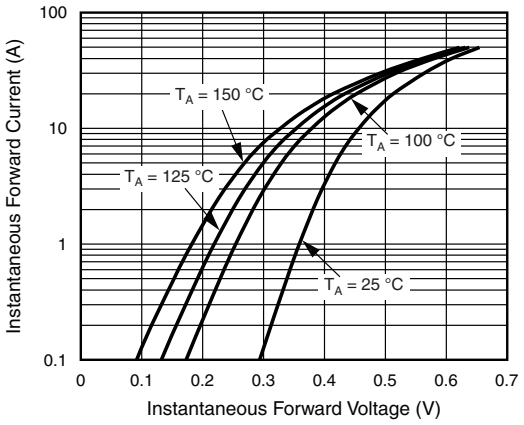


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

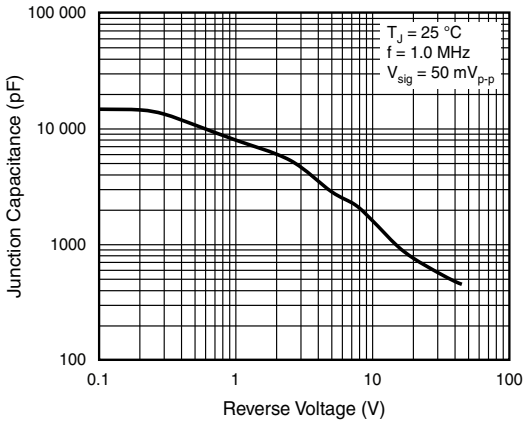


Fig. 5 - Typical Junction Capacitance Per Diode

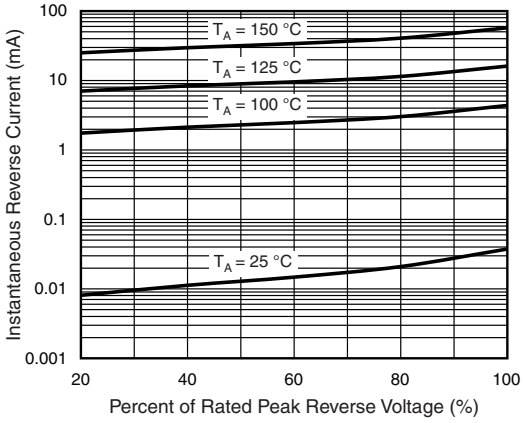


Fig. 4 - Typical Reverse Characteristics Per Diode

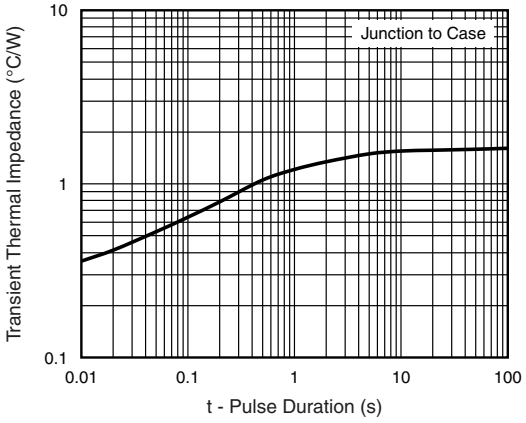
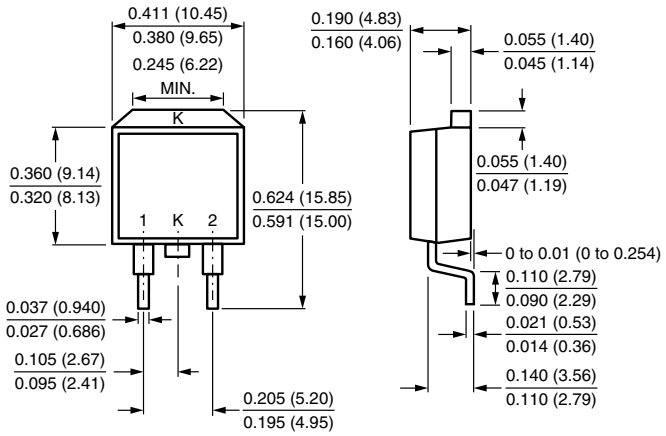


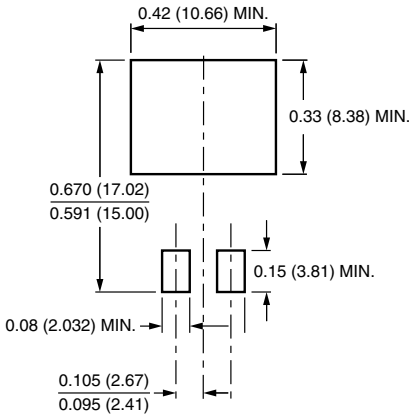
Fig. 6 - Typical Transient Thermal Impedance Per Diode

PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

TO-263AB



Mounting Pad Layout



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